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Zener Voltage Regulators

500 mW SOD−123 Surface Mount

MMSZ52xxxT1G Series, SZMMSZ52xxxT1G Series

Three complete series of Zener diodes are offered in the convenient, surface mount plastic SOD−123 package. These devices provide a convenient alternative to the leadless 34−package style. Zener voltage in this series are specified with device junction in thermal equilibrium.

Features

- 500 mW Rating on FR−4 or FR−5 Board
- Wide Zener Reverse Voltage Range − 2.4 V to 110 V @ Thermal Equilibrium*
- Package Designed for Optimal Automated Board Assembly
- Small Package Size for High Density Applications
- General Purpose, Medium Current
- ESD Rating of Class 3 (> 16 kV) per Human Body Model
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q101 Qualified and PPAP Capable
- These are Pb−Free Devices

Mechanical Characteristics:
CASE: Void-free, transfer-molded, thermosetting plastic case
FINISH: Corrosion resistant finish, easily solderable
MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES: 260°C for 10 Seconds
POLARITY: Cathode indicated by polarity band
FLAMMABILITY RATING: UL 94 V−0

MAXIMUM RATINGS

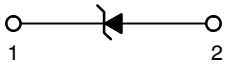
Rating	Symbol	Max	Units
Total Power Dissipation on FR−5 Board, (Note 1) @ T_L = 75°C Derated above 75°C	P_D	500 6.7	mW mW/°C
Thermal Resistance, Junction−to−Ambient (Note 2)	$R_{\theta JA}$	340	°C/W
Thermal Resistance, Junction−to−Lead (Note 2)	$R_{\theta JL}$	150	°C/W
Junction and Storage Temperature Range	T_J, T_{stg}	−55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
1. FR−5 = 3.5 X 1.5 inches, using the minimum recommended footprint.
2. Thermal Resistance measurement obtained via infrared Scan Method.

*For additional info on thermal equilibrium, please download, **onsemi** TVS/Zener Theory and Design Considerations Handbook, HBD854/D.



SOD−123
CASE 425
STYLE 1



MARKING DIAGRAM



XX = Device Code (Refer to page 3)
M = Date Code
▪ = Pb−Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
MMSZ52xxBT1G, SZMMSZ52xxBT1G	SOD−123 (Pb−Free)	3,000 / Tape & Reel
MMSZ52xxCT1G, SZMMSZ52xxCT1G	SOD−123 (Pb−Free)	3,000 / Tape & Reel
MMSZ52xxBT3G, SZMMSZ52xxBT3G	SOD−123 (Pb−Free)	10,000 / Tape & Reel
MMSZ52xxCT3G, SZMMSZ52xxCT3G	SOD−123 (Pb−Free)	10,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

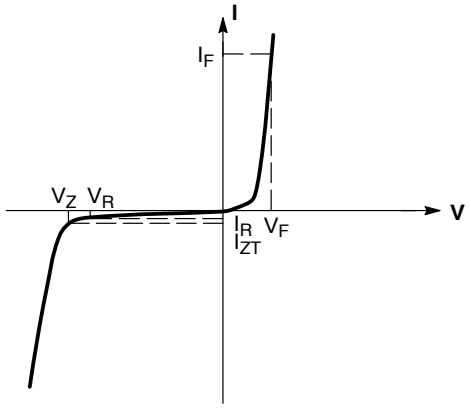
DEVICE MARKING INFORMATION

See specific marking information in the device marking column of the Electrical Characteristics table on page 3 of this data sheet.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted, V_F = 0.95 V Max. @ I_F = 10 mA)

Symbol	Parameter
V_Z	Reverse Zener Voltage @ I_{ZT}
I_{ZT}	Reverse Current
Z_{ZT}	Maximum Zener Impedance @ I_{ZT}
I_{ZK}	Reverse Current
Z_{ZK}	Maximum Zener Impedance @ I_{ZK}
I_R	Reverse Leakage Current @ V_R
V_R	Reverse Voltage
I_F	Forward Current
V_F	Forward Voltage @ I_F



Zener Voltage Regulator

5% TOLERANCE FG ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted, V_F = 0.9 V Max. @ I_F = 10 mA)

Device*	Device Marking	Zener Voltage (Notes 3 and 4)				Zener Impedance (Note 5)			Leakage Current	
		V_Z (Volts)			@ I_{ZT}	Z_{ZT} @ I_{ZT}	Z_{ZK} @ I_{ZK}		I_R @ V_R	
		Min	Nom	Max	mA	Ω	Ω	mA	μA	Volts
MMSZ5221BT1G	C1	2.28	2.4	2.52	20	30	1200	0.25	100	1
MMSZ5222BT1G	C2	2.38	2.5	2.63	20	30	1250	0.25	100	1
MMSZ5223BT1G	C3	2.57	2.7	2.84	20	30	1300	0.25	75	1
MMSZ5224BT1G	C4	2.66	2.8	2.94	20	30	1400	0.25	75	1
MMSZ5225BT1G	C5	2.85	3.0	3.15	20	29	1600	0.25	50	1
MMSZ5226BT1G	D1	3.14	3.3	3.47	20	28	1600	0.25	25	1
MMSZ5227BT1G	D2	3.42	3.6	3.78	20	24	1700	0.25	15	1
MMSZ5228BT1G	D3	3.71	3.9	4.10	20	23	1900	0.25	10	1
MMSZ5229BT1G	D4	4.09	4.3	4.52	20	22	2000	0.25	5	1
MMSZ5230BT1G	D5	4.47	4.7	4.94	20	19	1900	0.25	5	2
MMSZ5231BT1G	E1	4.85	5.1	5.36	20	17	1600	0.25	5	2
MMSZ5232BT1G	E2	5.32	5.6	5.88	20	11	1600	0.25	5	3
MMSZ5233BT1G	E3	5.70	6.0	6.30	20	7	1600	0.25	5	3.5
MMSZ5234BT1G	E4	5.89	6.2	6.51	20	7	1000	0.25	5	4
MMSZ5235BT1G	E5	6.46	6.8	7.14	20	5	750	0.25	3	5
MMSZ5236BT1G	F1	7.13	7.5	7.88	20	6	500	0.25	3	6
MMSZ5237BT1G	F2	7.79	8.2	8.61	20	8	500	0.25	3	6.5
MMSZ5238BT1G	F3	8.27	8.7	9.14	20	8	600	0.25	3	6.5
MMSZ5239BT1G	F4	8.65	9.1	9.56	20	10	600	0.25	3	7
MMSZ5240BT1G	F5	9.50	10	10.50	20	17	600	0.25	3	8
MMSZ5241BT1G	H1	10.45	11	11.55	20	22	600	0.25	2	8.4
MMSZ5242BT1G/T3G	H2	11.40	12	12.60	20	30	600	0.25	1	9.1
MMSZ5243BT1G	H3	12.35	13	13.65	9.5	13	600	0.25	0.5	9.9
MMSZ5244BT1G	H4	13.30	14	14.70	9.0	15	600	0.25	0.1	10
MMSZ5245BT1G	H5	14.25	15	15.75	8.5	16	600	0.25	0.1	11
MMSZ5246BT1G	J1	15.20	16	16.80	7.8	17	600	0.25	0.1	12
MMSZ5247BT1G	J2	16.15	17	17.85	7.4	19	600	0.25	0.1	13
MMSZ5248BT1G	J3	17.10	18	18.90	7.0	21	600	0.25	0.1	14
MMSZ5249BT1G	J4	18.05	19	19.95	6.6	23	600	0.25	0.1	14
MMSZ5250BT1G	J5	19.00	20	21.00	6.2	25	600	0.25	0.1	15
MMSZ5251BT1G	K1	20.90	22	23.10	5.6	29	600	0.25	0.1	17
MMSZ5252BT1G	K2	22.80	24	25.20	5.2	33	600	0.25	0.1	18
MMSZ5253BT1G	K3	23.75	25	26.25	5.0	35	600	0.25	0.1	19
MMSZ5254BT1G/T3G	K4	25.65	27	28.35	4.6	41	600	0.25	0.1	21
MMSZ5255BT1G	K5	26.60	28	29.40	4.5	44	600	0.25	0.1	21
MMSZ5256BT1G	M1	28.50	30	31.50	4.2	49	600	0.25	0.1	23
MMSZ5257BT1G	M2	31.35	33	34.65	3.8	58	700	0.25	0.1	25
MMSZ5258BT1G/T3G	M3	34.20	36	37.80	3.4	70	700	0.25	0.1	27
MMSZ5259BT1G	M4	37.05	39	40.95	3.2	80	800	0.25	0.1	30
MMSZ5260BT1G	M5	40.85	43	45.15	3.0	93	900	0.25	0.1	33
MMSZ5261BT1G	N1	44.65	47	49.35	2.7	105	1000	0.25	0.1	36
MMSZ5262BT1G	N2	48.45	51	53.55	2.5	125	1100	0.25	0.1	39
MMSZ5263BT1G	N3	53.20	56	58.80	2.2	150	1300	0.25	0.1	43
MMSZ5264BT1G	N4	57.00	60	63.00	2.1	170	1400	0.25	0.1	46
MMSZ5265BT1G	N5	58.90	62	65.10	2.0	185	1400	0.25	0.1	47
MMSZ5266BT1G	P1	64.60	68	71.40	1.8	230	1600	0.25	0.1	52
MMSZ5267BT1G	P2	71.25	75	78.75	1.7	270	1700	0.25	0.1	56
MMSZ5268BT1G	P3	77.90	82	86.10	1.5	330	2000	0.25	0.1	62
MMSZ5269BT1G	P4	82.65	87	91.35	1.4	370	2200	0.25	0.1	68
MMSZ5270BT1G	P5	86.45	91	95.55	1.4	400	2300	0.25	0.1	69
MMSZ5272BT1G/T3G	R2	104.5	110	115.5	1.1	750	3000	0.25	0.1	84

*Includes SZ-prefix devices where applicable.

3. "B" Suffix Type numbers shown have a standard tolerance of ±5% on the nominal Zener voltages.
4. Nominal Zener voltage is measured with the device junction in thermal equilibrium at T_L = 30°C ±1°C.
5. Z_{ZT} and Z_{ZK} are measured by dividing the AC voltage drop across the device by the ac current applied. The specified limits are for $I_{Z(AC)}$ = 0.1 $I_{Z(dc)}$ with the AC frequency = 1 kHz.

2% TOLERANCE FG ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted, V_F = 0.9 V Max. @ I_F = 10 mA)

Device*	Device Marking	Zener Voltage (Notes 6 and 7)				Zener Impedance (Note 8)			Leakage Current	
		V_Z (Volts)			@ I_{ZT}	Z_{ZT} @ I_{ZT}	Z_{ZK} @ I_{ZK}		I_R @ V_R	
		Min	Nom	Max	mA	Ω	Ω	mA	μA	Volts
MMSZ5226CT1G	TD	3.234	3.3	3.366	20	28	1600	0.25	25	1
MMSZ5231CT1G	TG	4.998	5.1	5.202	20	17	1600	0.25	5	2
MMSZ5232CT1G	TH	5.488	5.6	5.712	20	11	1600	0.25	5	3
MMSZ5245CT1G	TK	14.70	15	15.30	8.5	16	600	0.25	0.1	11
MMSZ5248CT1G	TL	17.64	18	18.36	7.0	21	600	0.25	0.1	14
MMSZ5250CT1G	TN	19.60	20	20.40	6.2	25	600	0.25	0.1	15
MMSZ5252CT1G	TQ	23.52	24	24.48	5.2	33	600	0.25	0.1	18
MMSZ5256CT1G	TW	29.40	30	30.60	4.2	49	600	0.25	0.1	23
MMSZ5258CT1G	TX	35.28	36	36.72	3.4	70	700	0.25	0.1	27

6. “C” Suffix Type numbers shown have a standard tolerance of ±2% on the nominal Zener voltages.
7. Nominal Zener voltage is measured with the device junction in thermal equilibrium at T_L = 30°C ±1°C.
8. Z_{ZT} and Z_{ZK} are measured by dividing the AC voltage drop across the device by the ac current applied. The specified limits are for $I_{Z(AC)}$ = 0.1 $I_{Z(dc)}$ with the AC frequency = 1 kHz.

*Includes SZ-prefix devices where applicable.

TYPICAL CHARACTERISTICS

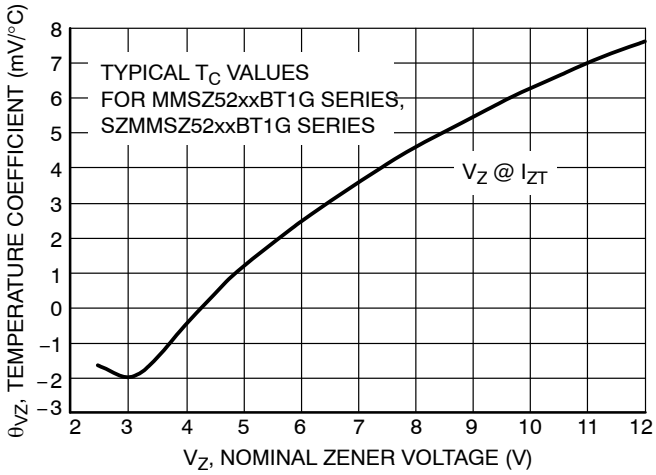


Figure 1. Temperature Coefficients (Temperature Range −55°C to +150°C)

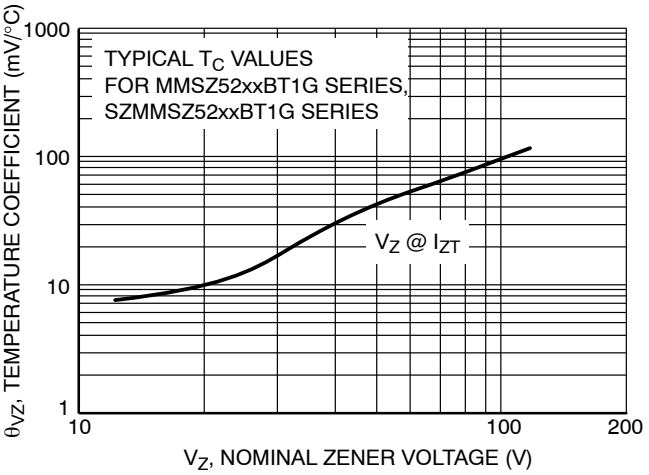


Figure 2. Temperature Coefficients (Temperature Range −55°C to +150°C)

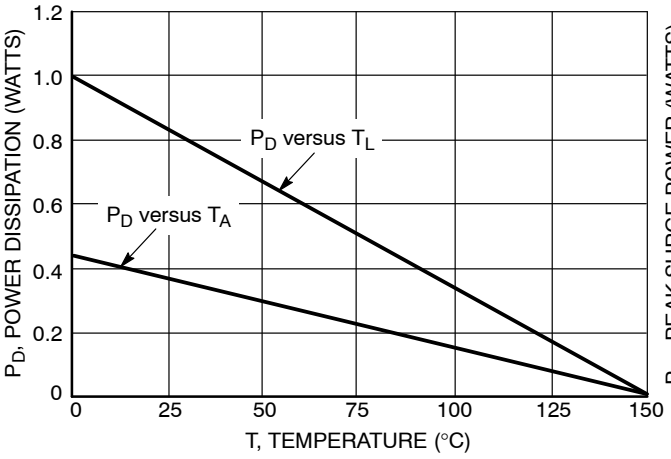


Figure 3. Steady State Power Derating

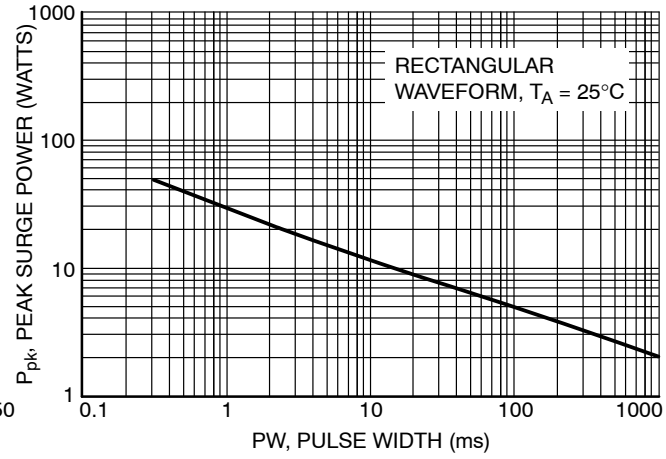


Figure 4. Maximum Nonrepetitive Surge Power

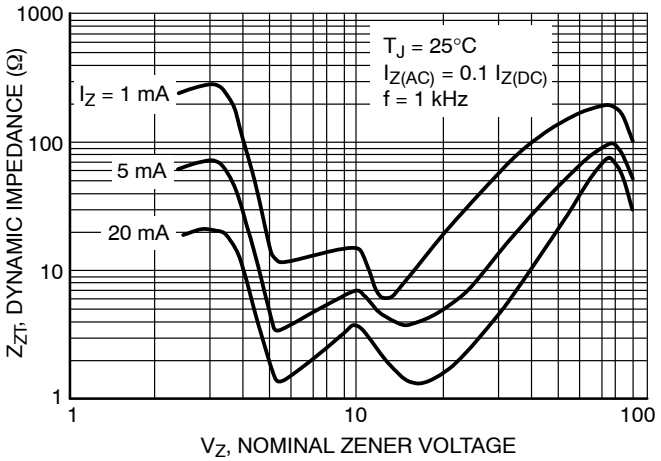


Figure 5. Effect of Zener Voltage on Zener Impedance

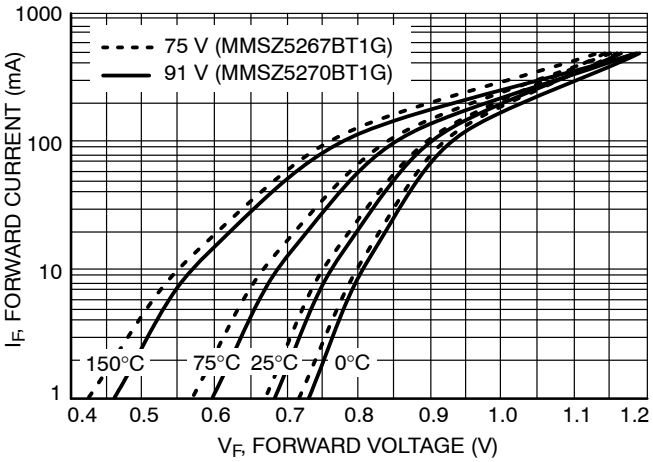


Figure 6. Typical Forward Voltage

TYPICAL CHARACTERISTICS

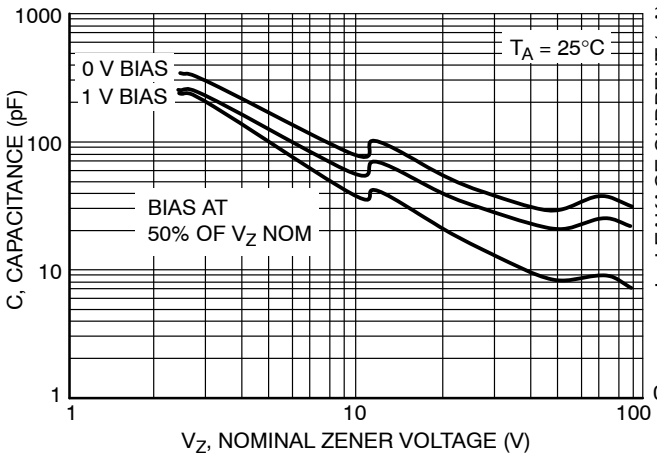


Figure 7. Typical Capacitance

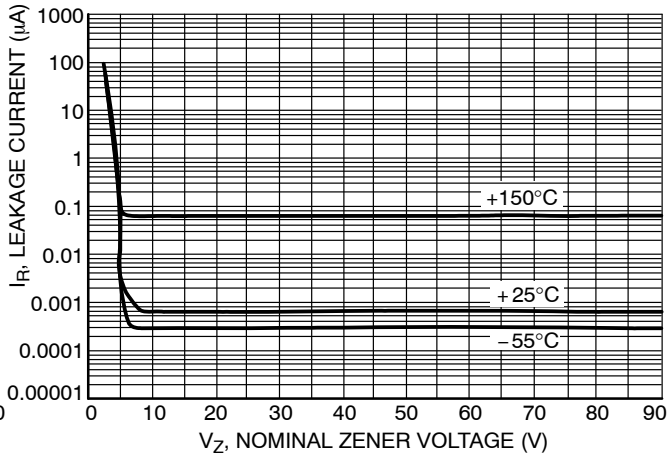


Figure 8. Typical Leakage Current

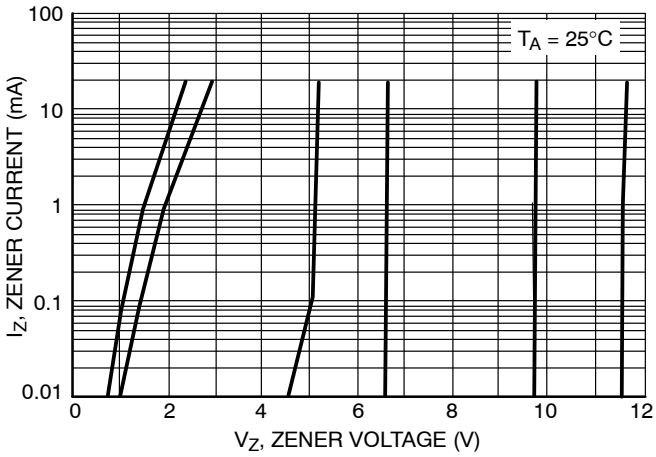


Figure 9. Zener Voltage versus Zener Current (V_Z Up to 12 V)

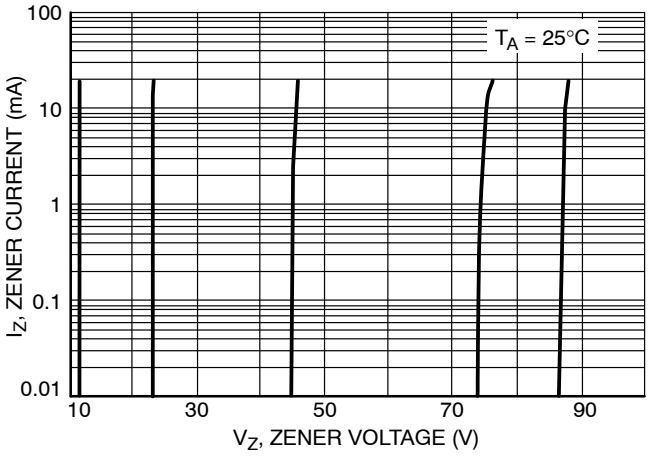


Figure 10. Zener Voltage versus Zener Current (12 V to 91 V)

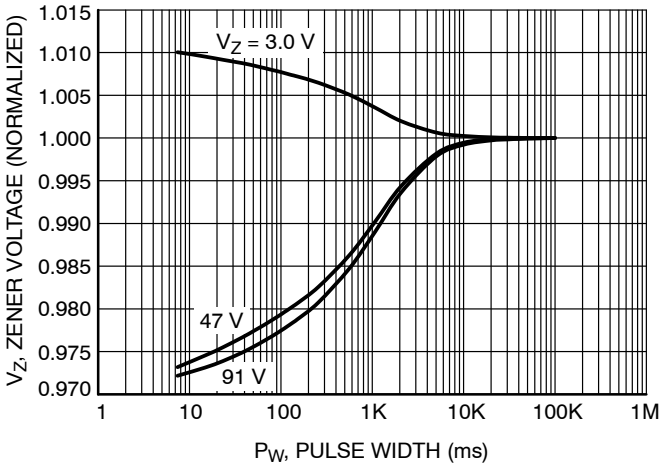
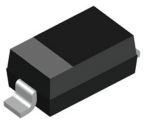
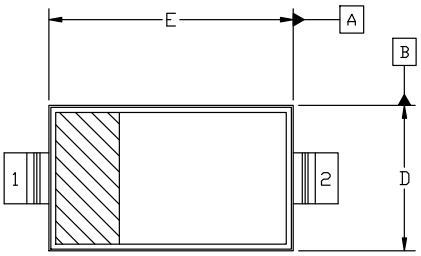


Figure 11. SOD−123 (plastic) 500 Watt Device

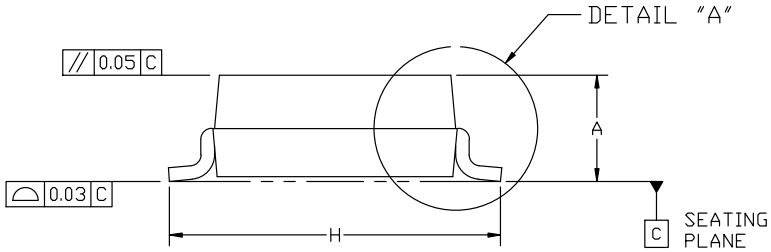


SOD−123 2−LEAD, 1.60x2.69x1.16
CASE 425
ISSUE H

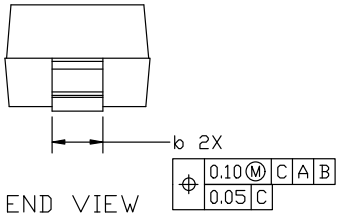
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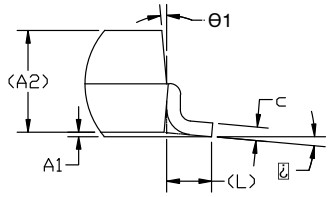
TOP VIEW



SIDE VIEW



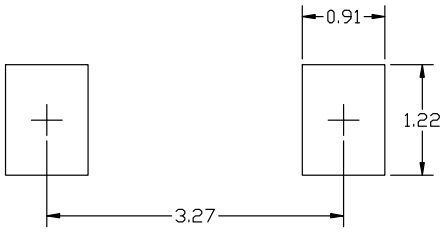
END VIEW



DETAIL "A"

NOTES:
1. DIMENSION AND TOLERANCING PER ASME Y14.5M, 2018
2. CONTROLLING DIMENSION: MILLIMETERS

	MILLIMETER		
DIM	MIN.	NOM.	MAX.
A	0.94	1.17	1.35
A1	0.00	0.05	0.10
A2		1.16 REF.	
b	0.51	0.61	0.71
c	–	–	0.15
D	1.40	1.60	1.80
E	2.54	2.69	2.84
H	3.56	3.68	3.86
L		0.25 REF.	
∠	0°		10°
θ1	0°		10°



RECOMMENDED MOUNTING FOOTPRINT

*For additional information on or Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference manual SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code
M = Date Code
▪ = Pb−Free Package
(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:
PIN 1. CATHODE
2. ANODE

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DESCRIPTION:	**SOD−123 2−LEAD, 1.60x2.69x1.16**	**PAGE 1 OF 1**

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